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N-Channel Depletion-Mode Vertical DMOS FET

Features

- High input impedance
- Low input capacitance
- Fast switching speeds
- Low on-resistance
- Free from secondary breakdown
- Low input and output leakage

Applications

- Normally-on switches
- Solid state relays
- Converters
- Linear amplifiers
- Constant current sources
- Telecom

General Description

This depletion-mode (normally-on) transistor utilizes an advanced vertical DMOS structure and Supertex's well-proven silicon-gate manufacturing process. This combination produces a device with the power handling capabilities of bipolar transistors and with the high input impedance and positive temperature coefficient inherent in MOS devices. Characteristic of all MOS structures, this device is free from thermal runaway and thermally-induced secondary breakdown.

Supertex's vertical DMOS FETs are ideally suited to a wide range of switching and amplifying applications where high breakdown voltage, high input impedance, low input capacitance, and fast switching speeds are desired.

Ordering Information

Part Number	Package Option	Packing
DN3765K4-G	TO-252 (D-PAK)	2000/Reel

-G denotes a lead (Pb)-free / RoHS compliant package.
Contact factory for Wafer / Die availablity.
Devices in Wafer / Die form are lead (Pb)-free / RoHS compliant.

Product Summary

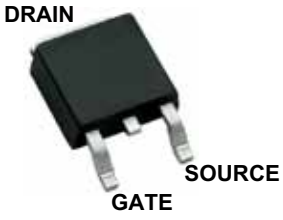
BV_{DSX}/BV_{DGX}	$R_{DS(ON)}$ (max)	I_{DSS} (min)
650V	8.0Ω	200mA

Absolute Maximum Ratings

Parameter	Value
Drain-to-source voltage	BV_{DSX}
Drain-to-gate voltage	BV_{DGX}
Gate-to-source voltage	±20V
Operating and storage temperature	-55°C to +150°C
Maximum junction temperature	150°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied. Continuous operation of the device at the absolute rating level may affect device reliability. All voltages are referenced to device ground.

Pin Configuration



TO-252 (D-PAK)

Typical Thermal Resistance

Package	θ_{ja}
TO-252 (D-PAK)	81°C/W

Product Marking

YY = Year Sealed
WW = Week Sealed
L = Lot Number
_____= "Green" Packaging

Package may or may not include the following marks: Si or

TO-252 (D-PAK)

Thermal Characteristics

Package	I_D (continuous)†	I_D (pulsed)	Power Dissipation ‡ @T_A = 25°C	I_{DR} †	I_{DRM}
TO-252 (D-PAK)	300mA	500mA	2.5W	300mA	500mA

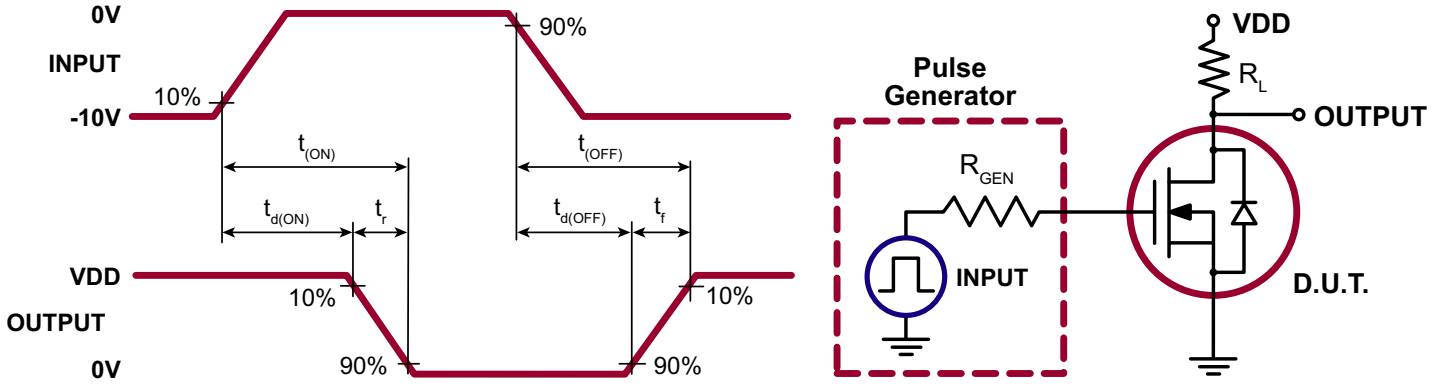
Notes:
† I_D *(continuous) is limited by max rated* T_j *of 150°C.*
‡ *Mounted on FR4 board, 25mm x 25mm x 1.57mm.*

Electrical Characteristics *(T_A = 25°C unless otherwise specified)*

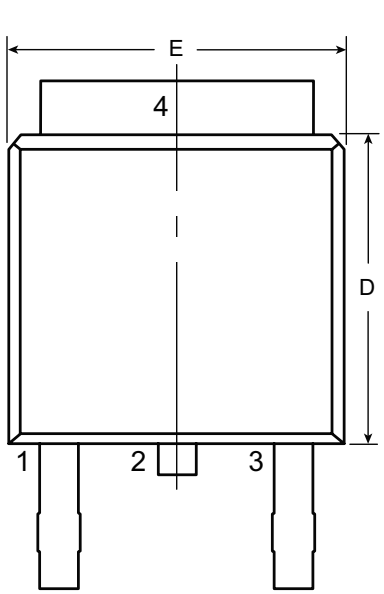
Sym	Parameter	Min	Typ	Max	Units	Conditions
BV_{DSX}	Drain-to-source breakdown voltage	650	-	-	V	V_{GS} = -5.0V, I_D = 100µA
$V_{GS(OFF)}$	Gate-to-source off voltage	-1.5	-	-3.5	V	V_{DS} = 25V, I_D= 10µA
$\Delta V_{GS(OFF)}$	Change in $V_{GS(OFF)}$ with temperature	-	-	-4.5	mV/°C	V_{DS} = 25V, I_D= 10µA
I_{GSS}	Gate body leakage current	-	-	100	nA	V_{GS} = ± 20V, V_{DS} = 0V
$I_{D(OFF)}$	Drain-to-source leakage current	-	-	10	µA	V_{GS} = -10V, V_{DS} = Max Rating
		-	-	1.0	mA	V_{GS} = -10V, V_{DS} = 0.8 Max Rating, T_A = 125°C
I_{DSS}	Saturated drain-to-source current	200	-	-	mA	V_{GS} = 0V, V_{DS} = 25V
$R_{DS(ON)}$	Static drain-to-source on-state resistance	-	-	8.0	Ω	V_{GS} = 0V, I_D = 150mA
$\Delta R_{DS(ON)}$	Change in $R_{DS(ON)}$ with temperature	-	-	1.1	%/°C	V_{GS} = 0V, I_D = 150mA
G_{FS}	Forward transductance	100	-	-	mmho	I_D = 100mA, V_{DS} = 10V
C_{ISS}	Input capacitance	-	-	825	pF	V_{GS} = -10V, V_{DS} = 25V, f = 1.0MHz
C_{OSS}	Common source output capacitance	-	-	190		
C_{RSS}	Reverse transfer capacitance	-	-	110		
$t_{d(ON)}$	Turn-on delay time	-	-	50	ns	V_{DD} = 25V, I_D = 150mA, R_{GEN} = 25Ω
t_r	Rise time	-	-	75		
$t_{d(OFF)}$	Turn-off delay time	-	-	75		
t_f	Fall time	-	-	100		
V_{SD}	Diode forward voltage drop	-	-	1.8	V	V_{GS} = -5.0V, I_{SD} = 200mA
t_{rr}	Reverse recovery time	-	800	-	ns	V_{GS} = -5.0V, I_{SD} = 200mA

Notes:
1. *All D.C. parameters 100% tested at 25°C unless otherwise stated. (Pulse test: 300µs pulse, 2% duty cycle.)*
2. *All A.C. parameters sample tested.*

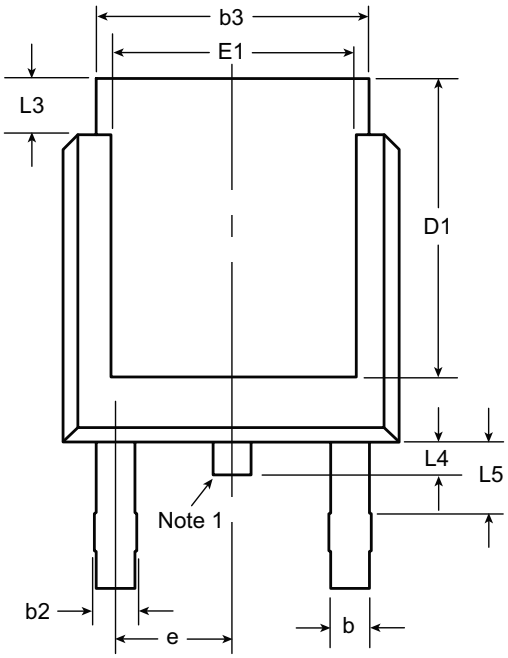
Switching Waveforms and Test Circuit



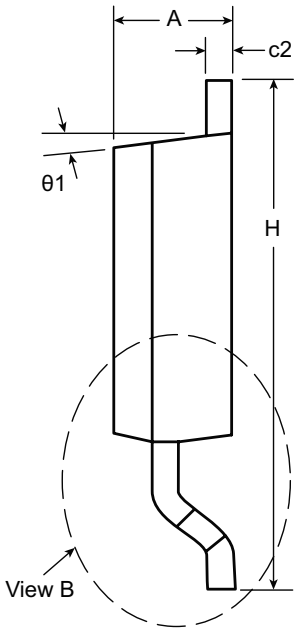
3-Lead TO-252 (D-PAK) Package Outline (K4)



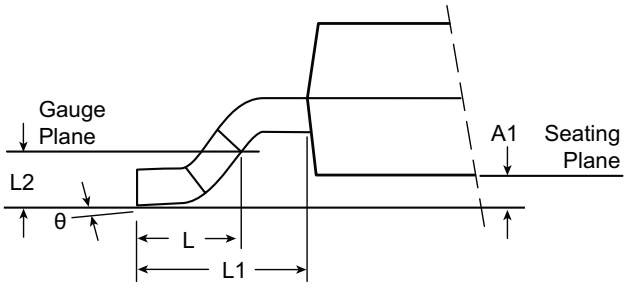
Front View



Rear View



Side View



View B

Note:

1. *Although 4 terminal locations are shown, only 3 are functional. Lead number 2 was removed.*

Symbol		A	A1	b	b2	b3	c2	D	D1	E	E1	e	H	L	L1	L2	L3	L4	L5	θ	θ1
Dimen-sion (inches)	MIN	.086	.000*	.025	.030	.195	.018	.235	.205	.250	.170	.090 BSC	.370	.055	.108 REF	.020 BSC	.035	.025*	.035†	0^0	0^0
	NOM	-	-	-	-	-	-	.240	-	-	-		-	.060			-	-	-	-	-
	MAX	.094	.005	.035	.045	.215	.035	.245	.217*	.265	.200*		.410	.070			.050	.040	.060	10^0	15^0

JEDEC Registration TO-252, Variation AA, Issue E, June 2004.
** This dimension is not specified in the JEDEC drawing.*
† This dimension differs from the JEDEC drawing.
Drawings not to scale.
Supertex Doc. #: *DSPD-3TO252K4, Version F040910.*

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to http://www.supertex.com/packaging.html.)

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